# H1'21 Financial results





### Disclaimer

This document is provided by Soitec (the "Company") for information purposes only.

The Company's business operations and financial position are described in the Company's 2019-2020 Universal Registration Document (which notably includes the 2019-2020 Annual Financial Report). The Company's 2019-2020 Universal Registration Document was filed with the AMF and is available on the Company's website in both French and English versions (<u>www.soitec.com</u>, in section "Company - Investors - Financial Reports").

Your attention is drawn to the risk factors described in Chapter 2.2 of the Company's 2019-2020 Universal Registration Document

This document contains summary information and should be read in conjunction with the 2019-2020 Universal Registration Document.

This document contains certain forward-looking statements. These forward-looking statements relate to the Company's future prospects, developments and strategy and are based on analyses of earnings forecasts and estimates of amounts not yet determinable. By their nature, forward-looking statements are subject to a variety of risks and uncertainties as they relate to future events and are dependent on circumstances that may or may not materialize in the future. Forward-looking statements are not a guarantee of the Company's future performance.

The Company's actual financial position, results and cash flows, as well as the trends in the sector in which the Company operates may differ materially from those contained in this document. Furthermore, even if the Company's financial position, results, cash-flows and the developments in the sector in which the Company operates were to conform to the forward-looking statements contained in this document, such elements cannot be construed as a reliable indication of the Company's future results or developments.

The Company does not undertake any obligation to update or make any correction to any forward-looking statement in order to reflect an event or circumstance that may occur after the date of this document. In addition, the occurrence of any of the risks described in Chapter 2.2 of the Universal Registration Document may have an impact on these forward-looking statements.

This document does not constitute or form part of an offer or a solicitation to purchase, subscribe for, or sell the Company's securities in any country whatsoever. This document, or any part thereof, shall not form the basis of, or be relied upon in connection with, any contract, commitment or investment decision.

Notably, this document does not constitute an offer or solicitation to purchase, subscribe for or to sell securities in the United States. Securities may not be offered or sold in the United States absent registration or an exemption from the registration under the U.S. Securities Act of 1933, as amended (the "Securities Act"). The Company's shares have not been and will not be registered under the Securities Act. Neither the Company nor any other person intends to conduct a public offering of the Company's securities in the United States.



### Outline









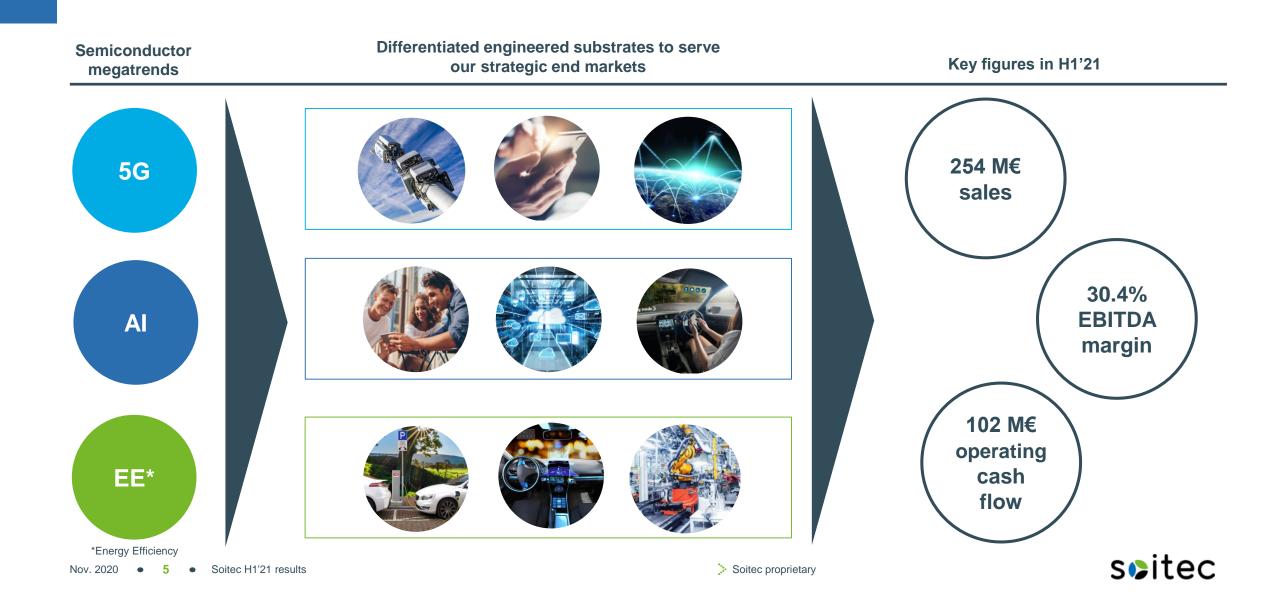
Nov. 2020 • 3 • Soitec H1'21 results

### Outline

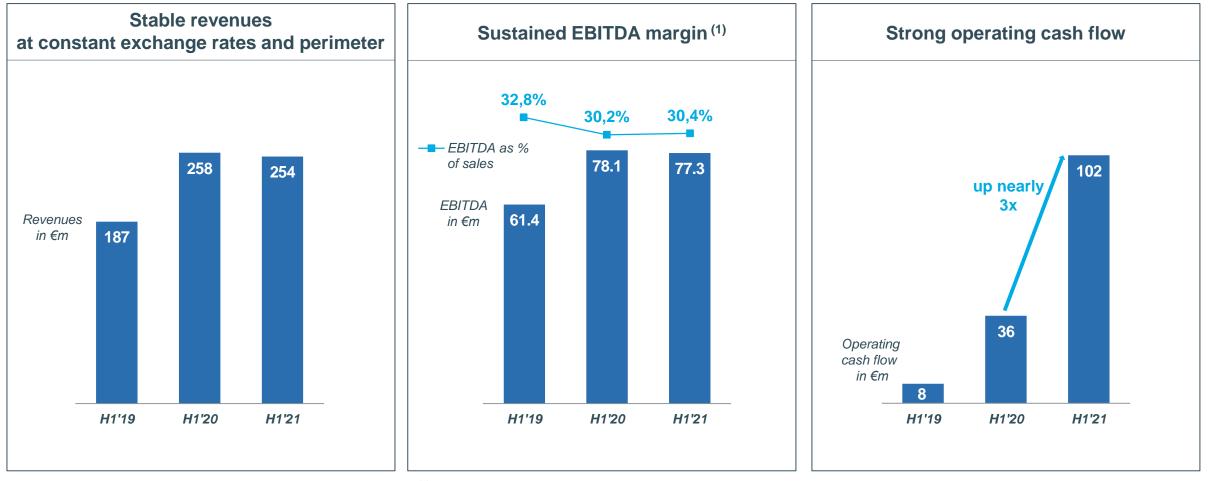




## H1'21 Highlights – Continuing our strong profitable growth and value creation trajectory



## H1'21 – Financial highlights



<sup>(1)</sup> EBITDA margin = Electronics EBITDA (EBITDA from continuing operations) / Sales



## H1'21 Highlights – Our priorities to manage the Covid-19 pandemic

### Protecting our people



# Operations and supply chain continuity



### Supporting our clients



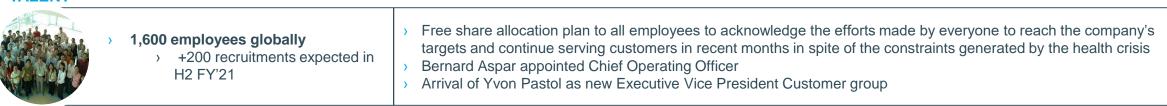
## Helping our community





## H1'21 Highlights – Steady expansion across the company to support profitable growth

### TALENT



### INNOVATION

<ul> <li>30 M€ invested in innovation</li> <li>&gt; Including 12 M€ in funding</li> <li>&gt; 15 new patents families</li> </ul>	<ul> <li>New POI products being developed with accelerated timeline</li> <li>Silicon Carbide: Development pilot line now installed and running in Substrate Innovation Center in Leti</li> <li>Demonstration of FD-SOI on high resistivity substrate to address additional 5G applications</li> <li>On the road to 200mm GaN on Silicon and integrating EpiGaN technologies into advanced engineered substrates</li> </ul>
---	--

### **SUPPLY CHAIN**



<ul> <li>Raw materials sourcing</li> <li>Long term contracts in place</li> </ul>	<ul> <li>Long term contracts in place to secure a clear and predictable spending in raw materials over the next 2 to 3 years</li> <li>Secured capacity expansion with manufacturing equipment vendors to support steep capacity ramp</li> </ul>
--	---



## H1'21 Highlights – Focus on Operations



- Bernin 3 (POI substrates)
  - Ramping at a very fast pace: H1'21 capacity x2 vs H2'20
  - > Full capacity target of 500 kwpy

### Hasselt (GaN substrates)

 High volume manufacturing MOCVD tool under qualification

### 200 mm

### Bernin 1 (SOI substrates)

- > Running close to full capacity in H1'21
- > Strong demand in RF-SOI
- > Lower demand in Power-SOI

### Simgui (SOI substrates)

 Qualified for larger products portfolio (RF, automotive)

### 300 mm

### Bernin 2 (SOI substrates)

- > Reached lower utilization rate in H1'21
- Back to full capacity expected in H2'21
- Awarded "Factory of the year" in France thanks to Industry 4.0 initiatives

### Singapore (SOI substrates)

- Capacity expansion for refresh and epitaxy (RF-SOI)
- Installing SOI capacity to prepare strong production ramp in FY'22











\* Source: Usine Nouvelle (October 2020)

### Outline







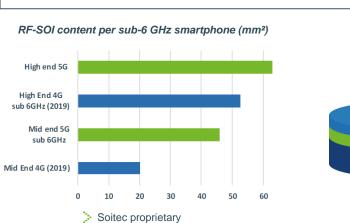
H1'21 Highlights	Market dynamics
Established standard for smartphone RF front-end modules	Global smartphone market to decline ~10% Y/Y in 2020
> Cellular: mainstream for switch, low-noise amplifiers, antenna tuners	Strong global smartphone rebound expected in 2021
<ul> <li>Connectivity: RF-SOI adoption for RFFE Wi-Fi 6 solutions including power amplifiers</li> </ul>	<ul> <li>5G smartphones shipment estimated at 225Mu in CY20 and above 500 M units in CY21</li> </ul>
Strong demand in both 200 mm and 300 mm fueled by 5G	<ul> <li>Strong 5G adoption in China (sub-6 GHz)</li> </ul>
> 200 mm remains solid and in high volumes	<ul> <li>Major smartphone OEM introducing mmW models</li> </ul>
> Strong 300 mm demand growing fast at all major foundries	5G smartphones to drive significant RF-SOI content increase
Soitec technology leadership	<ul> <li>Sub-6 GHz: in average RF-SOI content 60% higher on 5G vs 4G and up to 100% for mid Tier phones</li> </ul>
<ul> <li>Developing product roadmaps covering both high end to low end markets addressing 5G sub-6 GHz, mmW and Wi-Fi 6</li> </ul>	> mmW: RF-SOI design wins confirmed for indoor access point (infrastructure)
	> Wi-Fi 6: RF-SOI design wins in Wi-Fi 6 and Wi-Fi 6E MU-MIMO RF FE

#### 100% penetration in 4G/5G



### Global smartphone shipments (M units)

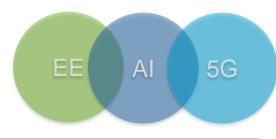




#### RF-SOI substrates



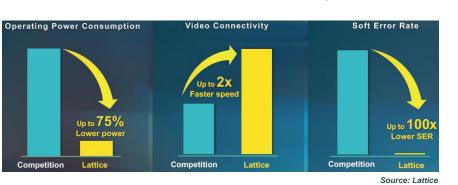




H1'21 Highlights	Market dynamics
Advances in FD-SOI technology, foundry offering and recognition	FD-SOI continues adoption for ultra low power applications
<ul> <li>Lattice wins EM Best-in-Industry for CrossLink FPGA platform</li> </ul>	Adding radio connectivity to the cloud with RF-to-Bits SoC(s) managed by AI &
> ST Microelectronics unveils Stellar MCU platform	using next-generation Soitec
<ul> <li>Globalfoundries unveils 22FDX RF+, advancing RF capabilities</li> </ul>	> Cost-efficient integrated radio in 5G (mmWave), Wi-Fi 6 & radar
<ul> <li>Dual-mode Bluetooth IP in 22FDX reduces power consumption by 50% while extending into through wireless stereo / hearing aid applications</li> </ul>	<ul> <li>Energy-efficient analog / mixed-signal solutions (data converter)</li> </ul>
<ul> <li>Samsung Foundry Forum (SAFE) promotes FD-SOI + eMRAM as foundry-first</li> </ul>	<ul> <li>Compute-efficient automotive with eMRAM memory</li> </ul>
	<ul> <li>Next-generation Soitec solution for Sub-THz design</li> </ul>
FD-SOI Edge processors (e.g., GreenWaves GAP9) adapts power per application	FD-SOI connects the cloud with low power efficiency and new architecture
300 mm FD+HR wafers sampling for next-generation 5G, radar, Sub-THz	Foundries developing technology nodes at 18nm and 12nm

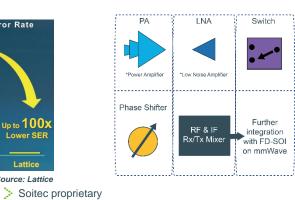
#### "Vision" processors for autonomous driving





#### Lattice Semiconductor FD-SOI based "Nexus" FPGA platform



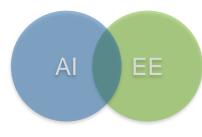


#### Synaptics 22nm FD-SOI far-field voice processing



ssitec

## Specialty-SOI Business Unit

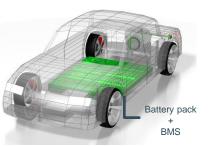


H1'21 Highlights	Market dynamics
<ul> <li>Power-SOI for management control</li> <li>Limited automotive revenue but secured by long term contract, product extension in 300 mm confirmed</li> </ul>	<ul> <li>Automotive market – Weak demand in 2020, solid recovery ahead</li> <li>Innovation to fuel Power-SOI demand for Battery Management System (BMS) and high voltage gate drivers based on SOI</li> </ul>
<ul> <li>Imager-SOI for facial recognition</li> <li>Sustained facial recognition demand for high-end smartphones</li> <li>Photonics-SOI as a standard for datacenters optical transceivers</li> <li>Steady demand of multiple IDMs and foundries for 100G transceivers</li> </ul>	<ul> <li>3D sensing for smartphones</li> <li>&gt; Success of facial recognition smartphones expected</li> <li>&gt; Image sensing is expending with demanding features</li> <li>Datacenters demand – Healthy growth for cloud data center traffic</li> <li>&gt; 400G Silicon Photonics</li> </ul>
	Proof-of-concept for co-packaged optics

#### Power-SOI for management control



#### Power-SOI opportunities for BMS



### Imager-SOI for facial recognition



#### Photonics-SOI for datacenters



ssitec

### **Filters Business unit**

H1'21 Highlights	Market dynamics
<ul> <li>POI – Ideal substrate to extend SAW filters technology reach, new paradigm addressing Sub-6 GHz</li> <li>&gt; Signed business agreement with Qualcomm Technologies on supply of POI substrates for 4G/5G RF filters</li> <li>&gt; Accelerating 150 mm POI ramp in high volume manufacturing</li> <li>&gt; Preparing fab expansion to reach 500K wafers/year</li> <li>Frec n sys – Accelerating POI product development and adoption</li> </ul>	<ul> <li>5G Sub-6 GHz adoption driving the demand for new high-performance filters</li> <li>POI substrates bring the performance (larger bandwidth, lower loss, superior temperature stability, efficient rejection) required for 5G filters</li> <li>Product roadmap to address several bands and new 5G requests</li> </ul>





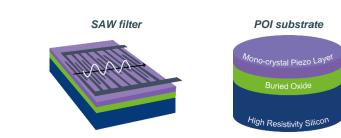
 Smart Cut POI
 Hybrid BAW/

 BAW
 Hybrid BAW/

 TC-SAW
 Item Band
 Ultra High Band

 600MHz
 1GHz
 1.4GHz
 1.6GHz
 1.7GHz
 2.7GHz
 3.3GHz
 5.9GHz

Filters technologies and POI positioning



Soitec POI substrate







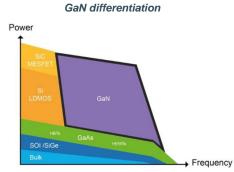
scitec

H1'21 Highlights	Market dynamics
<ul> <li>Successful integration within Soitec</li> <li>Continue production ramp and synergies with Soitec manufacturing</li> <li>Multiple customer qualifications on-going</li> <li>RF GaN/Silicon (150 mm-200 mm) in IDMs and foundries</li> </ul>	<ul> <li>GaN epiwafers for RF</li> <li>Base stations: strong traction for GaN RF infrastructure (power amplifiers)</li> <li>Smartphones: GaN/Si considered for 5G mmWave and sub-6 GHz (power amplifiers)</li> </ul>
<ul> <li>Product roadmap</li> <li>New products in 200 mm for both RF and Power applications</li> <li>Gan/Silicon and GaN/Silicon carbide</li> </ul>	GaN epiwafers for Power > Start customer evaluation of GaN/Si for Power (200 mm)

#### GaN epiwafer for 5G base stations, smartphone power amplifiers



Nov. 2020 • 15 • Soitec H1'21 results



Source: Figure adapted from Analog Device 2017

## GaN epiwafer substrate Surface Passivation III-Nitride Barrier layer Active GaN channel Buffer layer Si or SiC Substrate



## **Compounds Business Unit**

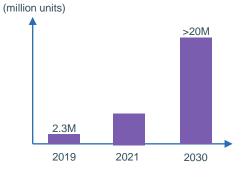


H1'21 Highlights	Market dynamics
<ul> <li>Smart Cut<sup>™</sup> based Silicon Carbide</li> <li>Pilot line fully operational as per plan jointly with Applied Materials</li> <li>First R&amp;D samples delivered</li> <li>Smart Cut<sup>™</sup> technology capability validated through test device results</li> </ul>	<ul> <li>Silicon Carbide</li> <li>Qualification products ready in calendar Q121</li> <li>Strategic interest from major automotive device/system makers</li> </ul>

#### SiC substrates for electric vehicles

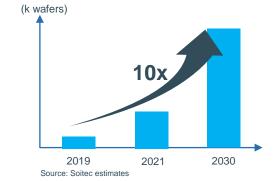


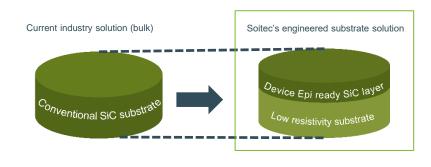
#### Electric vehicles demand (M units)



#### Projected SiC wafers demand

#### Soitec SiC engineered substrate solution

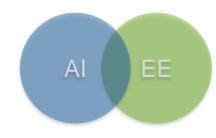




Source: Soitec estimates





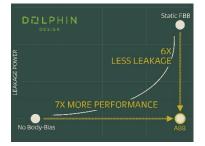


H1'21 Highlights	Market dynamics
<ul> <li>IP business</li> <li>More than 20 GlobalFoundries-FD-SOI Adaptative-Body-Biasing IP licenses</li> <li>Launched new IP R&amp;D (focused on 22nm FD-SOI &amp; 22nm ultra low leakage)</li> <li>Introduced energy-efficient MCU sub-system platform for IoT (audio, MEMS)</li> </ul>	<ul> <li>IP business</li> <li>Introduce DSP platform to address AI &amp; edge applications (smart meters)</li> <li>Launch of new platforms: power management, MCU sub-system, digital signal processing (standard and AI with neuronal networks), audio detection and emission</li> </ul>
ASIC	<ul> <li>Launch FD-SOI demo-chip for "Silicon proven" IP platforms.</li> </ul>
<ul> <li>Re-built solid physical implementation teams</li> <li>Strengthening of aerospace and defense business development</li> <li>1<sup>st</sup> design wins in consumer IoT (wearables, video codec)</li> </ul>	ASIC <ul> <li>Leverage IP platforms on AloT, industrial &amp; defense</li> </ul>



IP for earbuds

IP for wearables







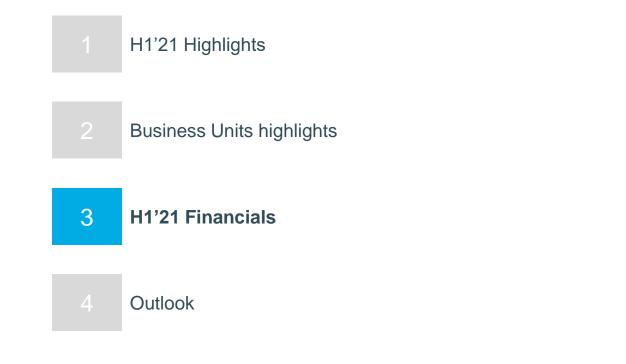


IP for smart meters



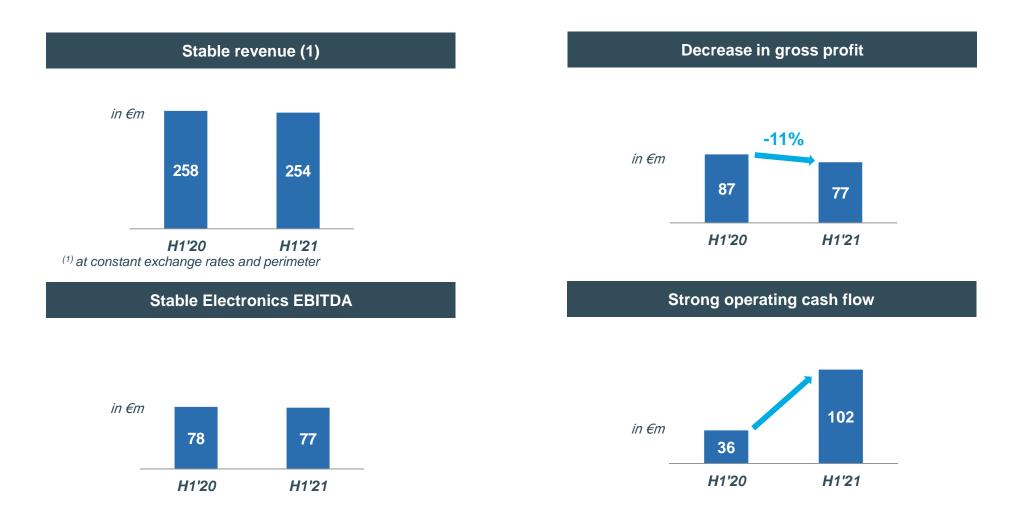
ASIC for aerospace

### Outline





## H1'21 Highlights



The income and expenses related to discontinued operations are directly reported as "Net result from discontinued operations". Down to the line "Net result after tax from continuing operations", the Group consolidated P&L account exclusively and fully reflects the Electronics activities as well as corporate expenses.



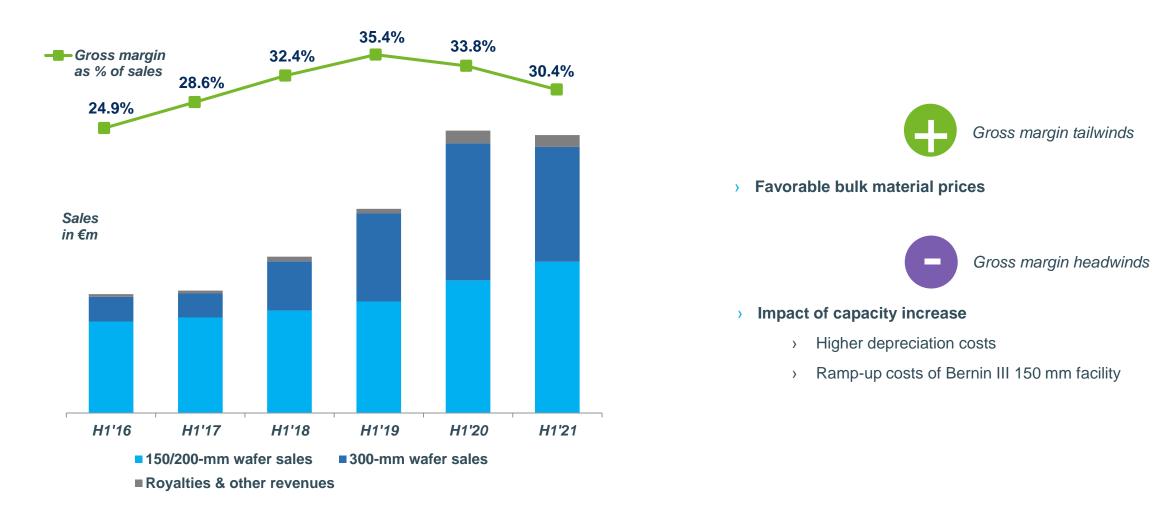
## H1'21 Sales performance

In €m	H1'21	H1'20	Change	evs H1'20	H1'21	Sales brea	akdown
			%	% at constant FX and scope		!%	
150/200 mm wafer sales	138	121	+14%	+15%			■ 150/200 mm
300 mm wafer sales	105	125	-16%	-15%	41%	54%	■ 300 mm
Royalties and other revenues	10	11	-8%	-8%			= 300 mm
Total sales	254	258	-1.6%	-0.4%	-		<ul> <li>Royalties and other revenues</li> </ul>

<b>150/200-mm wafer sales up 15%</b> (at constant exchange rates)	<b>300-mm wafer sales down 15%</b> (at constant exchange rates)	Royalties and other revenues down 8%
<ul> <li>&gt; Slight increase in volumes</li> <li>&gt; More favorable product mix</li> <li>&gt; Sustained growth in RF-SOI</li> <li>&gt; Lower sales of Power-SOI</li> <li>&gt; POI sales ramp-up</li> </ul>	<ul> <li>Lower sales essentially reflects decline in volumes</li> <li>Sales of RF-SOI 300-mm remained at high level</li> <li>Significantly lower sales of FD-SOI</li> <li>Robust sales of Photonics-SOI and Imager-SOI</li> </ul>	<ul> <li>Includes €8.5m contribution from Frec n sys, Dolphin Design and EpiGaN</li> </ul>



### **Gross margin evolution**





## **Current operating income**

In €m	H1'21	H1'20	Change
Sales	254.4	258.5	-2%
Gross profit	77.4	87.4	-11%
As a % of sales	30.4%	33.8%	
Gross R&D expenses	(31.2)	(30.8)	+1%
Prototype sales and others	1.5	4.1	-64%
Subsidies and income tax credit	12.2	10.7	+14%
Net R&D expenses	(17.5)	(16.0)	+10%
As a % of sales	6.9%	6.2%	,
Sales & Marketing expenses	(5.5)	(4.9)	+12%
General and administrative expenses	(17.3)	(15.3)	+13%
Total SG&A expenses	(22.7)	(20.2)	+13%
As a % of sales	8.9%	7.8%	
Current operating income	37.2	51.3	-28%
As a % of sales	14.6%	19.9%	

- Net R&D expenses up 10%, represents less than 7% of sales:
  - Slightly higher gross R&D expenses
    - > Higher resources allocated to projects
    - > Higher depreciation
  - > Lower prototype sales
  - > Higher subsidies and research tax credits

### > SG&A expenses up 13%, remains at less than 9% of sales:

- Increase in charges related to employee compensation schemes
  - Higher number of employees
  - > Share-based payment plans
- Continued effort to structure the Group in order to support future growth

The income and expenses related to discontinued operations are directly reported as "Net result from discontinued operations". Down to the line "Net result after tax from continuing operations", the Group consolidated P&L account exclusively and fully reflects the Electronics activities as well as corporate expenses.



### Net profit

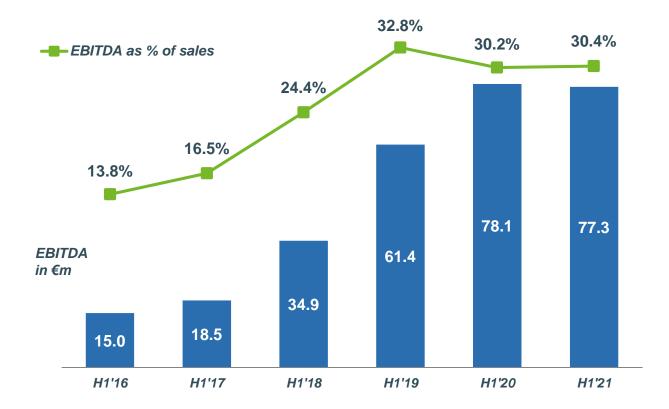
In €m	H1'21	H1'20
Current operating income	37.2	51.3
Other operating income and expenses	(0.0)	1.8
Operating income	37.1	53.2
Financial expenses	(3.8)	(3.8)
Net foreign exchange gain / (loss)	(6.4)	2.1
Net financial result	(10.2)	(1.7)
Income tax	(4.8)	(9.9)
Net profit from continuing operations	22.2	41.6
Net loss from discontinued operations	(0.0)	(0.0)
Net profit (Group share)	22.2	41.5

- In H1'20, other operating income included a gain on the disposal of an industrial site
- > Net financial loss:
  - Stable financial expenses (mostly includes noncash financial interests related to OCEANEs 2023)
  - Net foreign exchange loss of €(6.4)m recorded in H1'21 vs a gain of €2.1m in H1'20
- > Income tax continues to benefit from tax loss carryforwards

The income and expenses related to discontinued operations are directly reported as "Net result from discontinued operations". Down to the line "Net result after tax from continuing operations", the Group consolidated P&L account exclusively and fully reflects the Electronics activities as well as corporate expenses.



## Slight increase in Electronics EBITDA margin (continuing operations)



> H1'21 EBITDA almost stable

 H1'21 EBITDA margin slightly up despite lower gross margin



## Sharp increase in operating cash flow

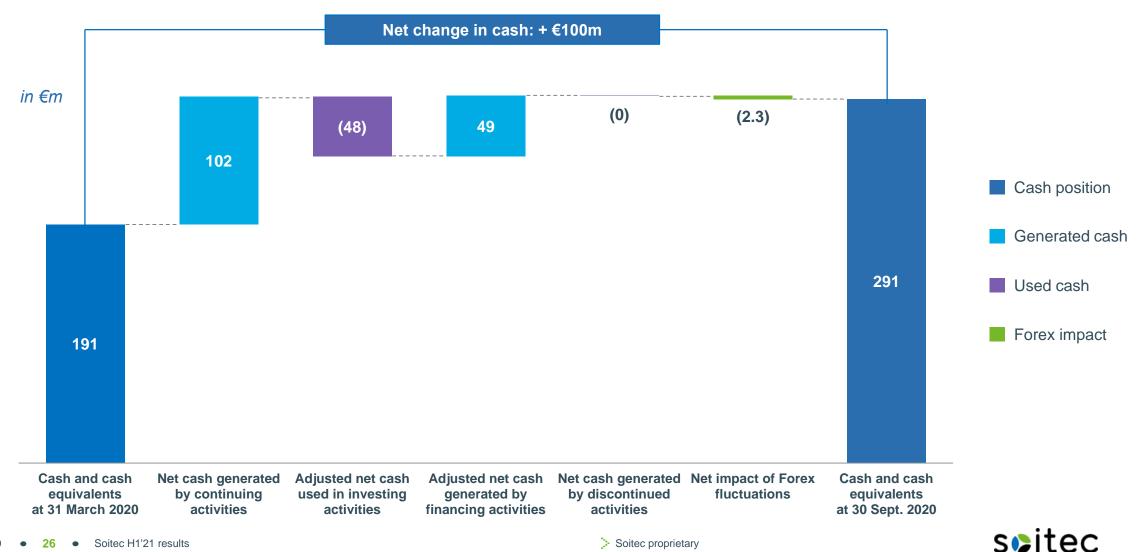
Operating cash-flows from continuing operations

In €m	H1'21	H1'20
Net profit	22.2	41.6
Depreciation and amortization	27.4	19.4
Other items	27.7	17.1
EBITDA	77.3	78.1
Change in working capital	31.2	(27.6)
Incl. inventories Incl. receivables Incl. others	(24) 60 (4.8)	(47) 21 (1.6)
Tax paid	(6.3)	(14.2)
Net cash generated by operating activities	102.3	36.3

→ <b>40%</b>	increase in D&A, mainly resulting from:
)	Continuous investments carried out in previous years
> Stror	ng decrease in WCR due to:
>	Sharp decrease in accounts receivables: -€60m
>	Partially offset by:
	<ul> <li>Higher level of inventories to meet sequential sales increase expected in H2'21: +€24m</li> </ul>
	<ul> <li>Decrease in other liabilities</li> </ul>
>	€31m decrease in WCR compares to €28m increase in H1'20
	m cash generated by operating activities, up nearly fold versus H1 FY'20

spitec

### Strong increase in cash position



## **Balance sheet**

In €m	30 Sept 2020	31 March 2020
Intangible assets	92	88
Tangible assets	324	297
Other non-current assets	30	23
Deferred tax assets	37	37
Total non-current assets	482	445
Inventories	144	123
Trade receivables	112	167
Other current assets	70	74
Cash and cash equivalents	291	191
Total current assets	617	556
Total assets	1 099	1 001

## In €m

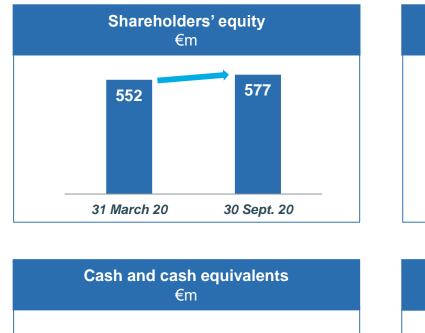
 30 Sept
 31 March

 2020
 2020

Total equity	577	552
Long-term financial debt	254	193
Provisions and other non-current liabilities	44	41
Total non-current liabilities	297	233
Trade payables	70	76
Other current liabilities	113	88
Short-term financial debt	43	52
Total current liabilities	225	217
Total liabilities and equity	1 099	1 001



## A solid financial structure



291

30 Sept. 20



Gross debt

€m

245

31 March 20

297

30 Sept. 20

### Equity further reinforced:

> Mainly thanks to H1'21 result

### → Gross debt increased by €52m:

 > €58m first partial drawdown on €200m L/T loan granted by Banque des Territoires as part of Nano 2022 plan

### > Increase in cash position reflects:

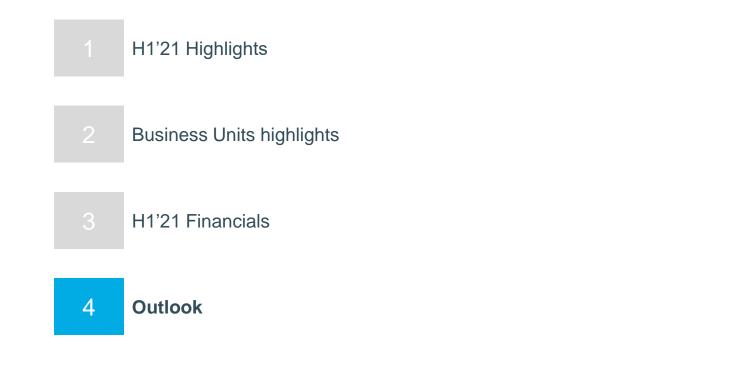
- > Strong free cash-flow
- > New financing
- > Net debt / Equity ratio: 0.01

191

31 March 20



### Outline





### Outlook – FY'21 & FY'22

### FY'21 guidance

- > Confirmed stable revenues at constant exchange rates and perimeter
- Confirmed Electronics EBITDA margin of around 30%
- > Planned Electronics adjusted net cash out related to CAPEX of €135m vs. at least €100m previously announced

### FY'22 outlook

> Revenues now expected above \$900m (i.e. above €800m based on a €/\$ rate of 1.13)



# Thank you

## Follow us on:

✔ Soitec
✔ @Soitec\_FR / @Soitec\_EN
In Soitec







## seitec